

ESM101 THRU ESM106

SURFACE MOUNT GLASS PASSIVATED SUPER FAST SILICON RECTIFIER

VOLTAGE RANGE 50 to 400 Volts CURRENT 1.0 Ampere

FEATURES

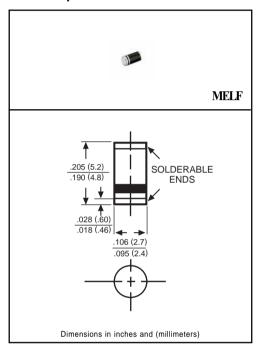
- * Fast switching
- * Glass passivated device
- * Ideal for surface mounted applications
- * Low leakage current
- * Metallurgically bonded construction
- * Mounting position: Any
- * Weight: 0.015 gram

MECHANICAL DATA

* Epoxy : Device has UL flammability classification 94V-0

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 $^{\circ}$ C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.



MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	ESM101	ESM102	ESM103	ESM104	ESM105	ESM106	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	150	200	300	400	Volts
Maximum RMS Volts	VRMS	35	70	105	140	210	280	Volts
Maximum DC Blocking Voltage	VDC	50	100	150	200	300	400	Volts
Maximum Average Forward Current at TA = 55°C	lo	1.0					Amps	
Peak Forward Surge Current, IFM (surge): 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	IFSM	30						Amps
Typical Junction Capacitance (Note 2)	CJ	15 10					pF	
Operating and Storage Temperature Range	TJ, TSTG	-65 to + 175					°C	

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS		SYMBOL	ESM101	ESM102	ESM103	ESM104	ESM105	ESM106	UNITS
Maximum Forward Voltage at 1.0A DC		VF	0.95			25	Volts		
Maximum DC Reverse Current	@TA = 25°C	JR 5.0							uAmps
at Rated DC Blocking Voltage	@Ta =125°C	l ik	100						uzilips
Maximum Reverse Recovery Time (Note 1)		trr	35					nSec	

NOTES: 1. Test Conditions: IF=0.5A, IR=-1.0A, IRR=-0.25A.

2. Measured at 1 MHz and applied reverse voltage of 4.0 volts.

RATING AND CHARACTERISTIC CURVES (ESM101 THRU ESM106)

5/10 ns/cm

FIG. 1 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC 10 Ω NONINDUCTIVE $\begin{array}{c} \mathbf{50}\,\Omega \\ \mathbf{NONINDUCTIVE} \end{array}$ +0.5A D.U.T Ω (+)PULSE 25 Vdc GENERATOR -0.25A (approx) (NOTE 2) (;V) 1Ω OSCILLOSCOPE NON-(NOTE 1) INDUCTIVE -1.0A → 1cm ← SET TIME BASE FOR NOTES:1 Rise Time = 7ns max. Input Impedance = 1 megohm. 22 pF.

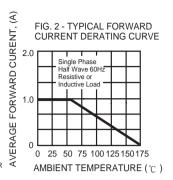


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

2. Rise Time = 10ns max. Source Impedance =

50 ohms.

100 INSTANTANEOUS REVERSE CURRENT, (uA) TJ = 150 ℃ 10 TJ = 100 ℃ 1.0 T,J = 25 °C .1 .01 60 80 100 120 PERCENT OF RATED PEAK REVERSE VOLTAGE, (%)

FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS 10 INSTANTANEOUS FORWARD CURRENT, (A) TJ = 25 ℃ Pulse Width = 300uS .01 1% Duty Cycle .001 0 1.0 INSTANTANEOUS FORWARD VOLTAGE, (V)

FIE 5 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

